

M74HC4851

Single 8-channel analog MUX/DEMUX with injection current

protection Datasheet – production data

Features

- Low power dissipation
 - $I_{CC} = 2 \mu A \text{ (max.) at } T_A = 25 \text{ °C}$
- Injection current protection
 - $V_{\Delta OUT}$ < 1 mV at V_{CC} = 5 V, $I_{IN} \le$ 1 mA
 - $R_S \leq 3.9 \text{ k}\Omega$
- "ON" resistance at T_A = 25 °C
 - 215 Ω typ. (V_{CC} = 3.0 V)
 - 160 Ω typ. (V_{CC} = 4.5 V)
 - 150 Ω typ. (V_{CC} = 6 V)
- Fast switching
- t_{pd} = 8.6 ns (typ.) at T_A = 25 °C, V_{CC} = 4.5 V
- Wide operating supply voltage range
 - V_{CC} = 2 V to 6 V
- High noise immunity
 - V_{NIH} = V_{NIL} = 28% V_{CC} (min.)
- Pin and function compatible with series 4051, 4851
- Latch-up performance exceeds 500 mA
 - (JESD 17)
- ESD performance
 - HBM: 2000 V
 - MM: 200 V
 - CDM: 1000 V



Applications

- Automotive
- Computer
- Consumer
- Industrial

Description

The M74HC4851 device is a single 8-channel analog multiplexer/demultiplexer manufactured with silicon gate C^2MOS technology.

It features injection current effect control which makes the device particularly suited for use in automotive applications where voltages in excess of normal logic voltages are common. The injection current effect control allows signals at disabled input channels to exceed the supply voltage range or go down to ground without affecting the signal of the enabled analog channel.

This eliminates the need for external dioderesistor networks typically used to keep the analog channel signals within the supply voltage range.

Table 1	Device	summary	

Order code	Temperature range	Package	Packaging	Marking
M74HC4851YRM13TR ⁽¹⁾	-40/+125 °C	SO-16 (automotive grade)	Tape and reel	74HC4851Y
M74HC4851RM13TR	-55/+125 °C	SO-16	Tape and reel	74HC4851
M74HC4851YTTR ⁽¹⁾	-40/+125 °C	TSSOP16 (automotive grade)	Tape and reel	HC4851Y
M74HC4851TTR	-55/+125 °C	TSSOP16	Tape and reel	HC4851

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

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This is information on a product in full production.

1 Pin connections

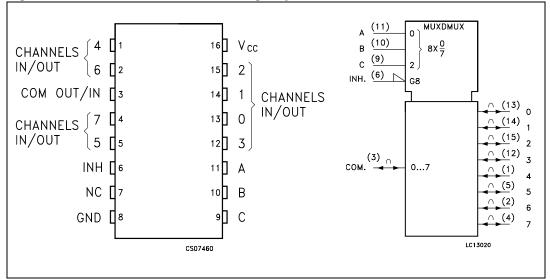


Figure 1. Pin connections and IEC logic symbols

Table 2. Pin descriptions

Pin number	Symbol	Name and function		
3	COM OUT/IN	Common output/input		
6	INH	INHIBIT input		
7	NC Not connect			
11, 10, 9	A, B, C	Select inputs		
13, 14, 15, 12, 1, 5, 2, 4	0 to 7	Independent input/outputs		
8	GND	Ground (0 V)		
16	V _{CC}	Positive supply voltage		



	Input	state		On channel
INH	С	В	Α	On channer
L	L	L	L	0
L	L	L	Н	1
L	L	Н	L	2
L	L	Н	Н	3
L	н	L	L	4
L	Н	L	Н	5
L	н	Н	L	6
L	Н	Н	Н	7
Н	Х	Х	Х	NONE

Table 3. Truth table

Note: X: don't care.

Figure 2. Control input equivalent circuit

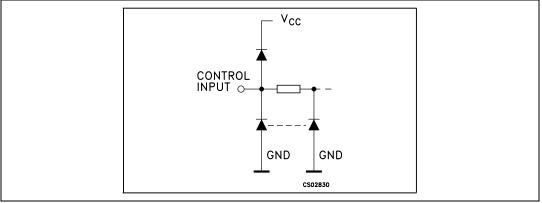
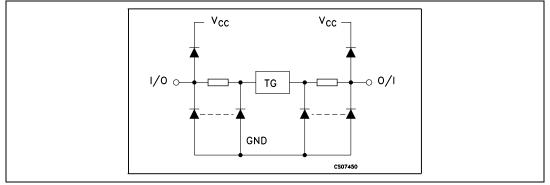
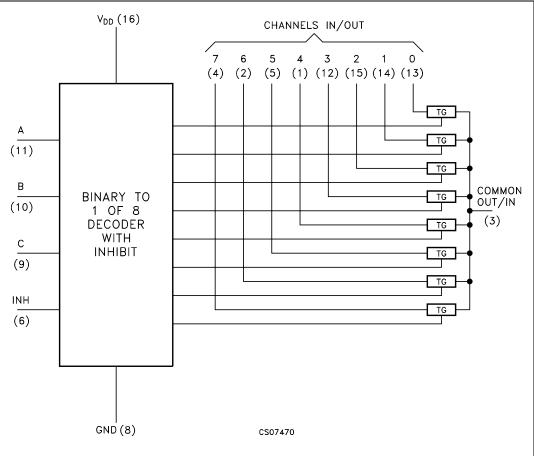


Figure 3. I/O equivalent circuit









2 Absolute maximum ratings and operating conditions

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Symbol	F	Parameter	Value	Unit
V _{CC}	Supply voltage		-0.5 to +7	V
V _{IN}	Control input voltage		-0.5 to V _{CC} + 0.5	V
V _{I/O}	Switch I/O voltage		-0.5 to V _{CC} + 0.5	V
I _{СК}	Control input diode current	± 25	mA	
I _{IOK}	I/O diode current	± 25	mA	
I _{CC}	DC V _{CC} or ground current	± 50	mA	
P	Dower dissinction	SO-16	500 ⁽¹⁾	mW
P _D	Power dissipation	TSSOP16	450 ⁽¹⁾	mW
T _{stg}	Storage temperature	-	-65 to +150	°C
ΤL	Lead temperature (10 sec.)		300	°C
	Human body model (HBM)		2000	V
ESD (JESD22)	Machine model (MM)	200	V	
(0-00000)	Charged device model (CDM)		1000	V

Table 4. Absolute maximum ratings

1. Power dissipation at 65 °C. Derating from 65 °C to 125 °C: SO package -7 mW/°C; TSSOP package -6.1 mW/°C.

Table 5. Recommended operating conditions

Symbol	P	arameter	Value	Unit	
V _{CC}	Supply voltage		2 to 6	V	
V _{I/O}	Input output voltage		0 to V _{CC}	V	
V _{I/O}	Static or dynamic voltage across	switch ⁽¹⁾	0 to 1.2	V	
V _{IN}	Control input voltage	0 to V _{CC}	V		
т	SO-16, TSSOP16		-55 to +125	°C	
T _{op}	Operating temperature	SO-16, TSSOP16 (automotive grade)	-40 to +125	°C	
		V _{CC} = 2.0 V	0 to 1000		
	Input rise and fall time ⁽²⁾	V _{CC} = 3.0.V	0 to 800		
t _r , t _f	(channel select or enable inputs	V _{CC} = 3.3 V	0 to 700	ns	
	only)	V _{CC} = 4.5 V	0 to 500		
		V _{CC} = 6.0 V	0 to 400		

For voltage drops across the switch greater than 1.2 V (switch on), excessive V_{CC} current may be drawn; i.e., the current
out of the switch may contain both V_{CC} and switch input components. The reliability of the device is unaffected unless the
maximum ratings are exceeded.

2. $V_{\rm IN}$ from 30% to 70% $V_{\rm CC}$ of channel selected or enable inputs.



			Test con	dition				Value)			
Symbol	Parameter	v _{cc}			Τ,	_A = 25	°C	Up to	85 °C	Up to 125 °C		Unit
		(V)			Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0			1.5			1.5		1.5		
		3.0			2.1			2.1		2.1		
V _{IHC}	High level input voltage	3.0			2.3			2.3		2.3		V
	i i i i i g i	4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
		2.0					0.5		0.5		0.5	
		3.0					0.9		0.9		0.9	
V _{ILC}	Low level input voltage	3.3					1.0		1.0		1.0	V
	Vollage	4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
		2.0	$I_S = 2 \text{ mA}$			500	650		670		700	
		3.0	I _S ≤2 mA	$V_{IN} = V_{IHC}$ or		215	280		320		360	
R _{ON}	ON resistance	3.3		V_{ILC}		210	270		305		345	Ω
		4.5		GND		160	210		240		270	
		6.0				150	195		220		250	
		2.0	$I_S = 2 \text{ mA}$			4	10		15		20	
	Difference of	3.0		V – V – or		2	8		12		16	Ω
ΔR_{ON}	ON resistance between	3.3	L < 0 m A	$V_{IN} = V_{IHC}$ or V_{ILC} $V_{IS} = V_{CC}/2$		2	8		12		16	
	switches	4.5	I _S ≤2 mA	$V_{IS} = V_{CC}/2$		2	8		12		16	
		6.0				3	9		13		18	
I _{OFF}	Input/output leakage current (switch off) (any channel)	6.0					±0.1		±0.5		±1.0	μA
I _{OFF}	Input/output leakage current (switch off) (common channel)	6.0	V _{IN} = V	′ _{CC} or GND			±0.2		±2		±4	μA
I _{ON}	Switch input leakage current (switch on, output open)	6.0	V _{IN} = V	′ _{CC} or GND			±0.1		±0.5		±1	μΑ

Table 6.DC specifications



			Test condition		Value							
Symbol	Parameter	V _{cc}		T _A = 25 °C		Up to 85 °C		Up to 125 °C		Unit		
		(Ŭ)	(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
I _{IN}	Control input current	6.0	$V_{IN} = V_{CC}$ or GND			±0.1		±0.1		±1	μA	
I _{CC}	Quiescent supply current	6.0	V _{IN} = V _{CC} or GND V _{IN(analog)} = GND			2		20		40	μA	

Table 6. DC specifications (continued)

Table 7.AC electrical characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 6 \text{ ns}$)

			Test condition				Value)			
Symbol	Parameter	v _{cc}		T,	<u>م</u> = 25 '	°C	Up to	85 °C	Up to	125 °C	Unit
		(Ÿ)	Test circuit 1	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0			19.5	25		29		32	
	Propagation	3.0			12	15.5		17.5		19.5	
t _{PHL} ,t _{PL}	delay time, analog input to	3.3			11	14.5		16.5		18.5	ns
	analog output	4.5			8.6	11.5		12.5		13.5	
		6.0			8	10		11		12	
		2.0			23	30		35		40	
	Propagation delay time	3.0			13.5	17.5		20		23	
t _{PHL,} t _{PLH}	channel-select	3.3			12.5	16.5		19		22	ns
1 211	to analog output	4.5			10	13		15		17	
		6.0			9.5	12.5		14.5		16.5	
		2.0				95		105		115	
t _{PHZ} ,	Enable disable time, enable or	3.0				90		100		110	
t _{PZH} t _{PLZ,}	channel-select	3.3				85		95		105	ns
t _{PZL}	to analog output	4.5				80		90		100	
		6.0				78		80		80	
C _{IN}	Input capacitance (digital pins)				3.5	10		10		10	pF
C _{IN}	Input capacitance (switches off, any single analog pins)				6.7	15		15		15	pF



		Test condition		Value							
Symbol	Parameter	v _{cc}	Test circuit 1	T _A = 25 °C			Up to 85 °C		Up to	125 °C	Unit
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
C _{IN}	Input capacitance (switches off, any common analog pins)				22	40		40		40	pF
-	Power	3.3			24						-
C _{PD}	dissipation capacitance ⁽¹⁾	5.0			28						pF

Table 7.AC electrical characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 6 \text{ ns}$) (continued)

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load (refer to *Figure 5*). The average operating current can be obtained by the following equation: $I_{CC}(opr) = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$.

Table 8.Injection current coupling specification ($T_A = -55^{\circ}C$ to $+125^{\circ}C$)

			Test condition	Va	lue	
Symbol	Symbol Parameter		Test circuit 2	Тур. ⁽¹⁾	Max.	Unit
		3.3		0.050	1.0	
		5.0	$I_{IN} \le 1 \text{ mA}, R_S \le 3.9 \text{ k}\Omega$	0.100	1.0	1
	Shift of output	3.3	l _{IN} ≤10 mA, R _S ≤ 3.9 kΩ	0.345	5.0	
V.	voltage of enabled	5.0	$I N \ge 10 IIIA, INS \ge 3.9 K22$	0.067	5.0	mV
V _{AOUT}	analog	$\begin{array}{c} 3.3\\ \hline 5.0 \end{array} \qquad \qquad I_{IN} \leq 1 \text{ mA, } R_{S} \leq 20 \text{ k}\Omega \end{array}$	L < 1 mA P < 20 kO	0.050	2.0	IIIV
	channel		$I_{ N } \leq I IIIA, \Pi_S \leq 20 \text{ km}$	0.110	2.0	
		3.3	I _{IN} ≤ 10 mA, R _S ≤ 20 kΩ	0.050	20	
		5.0	$\eta_N \simeq 10 \text{mm}, \text{ms} \simeq 20 \text{ksz}$	0.024	20	

1. Typical values are measured at $T_A = 25 \text{ °C}$. They are calculated as the difference from V_{OUT} without injection current and V_{OUT} with injection current. I_{IN} = total current injected into any other disabled channels, one at time.





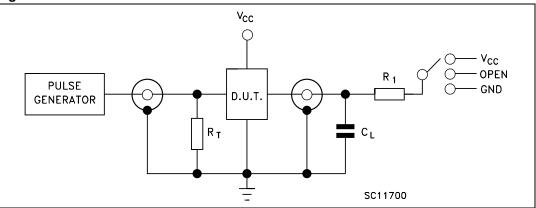


Table 9. Test circuit 1 - switch configuration table

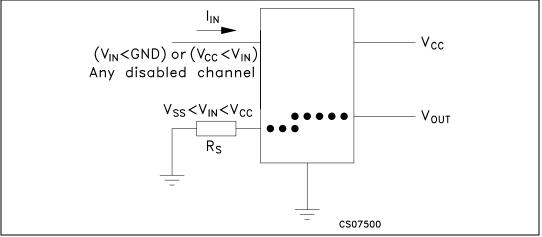
Test	Switch
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	V _{CC}
t _{PZH} , t _{PHZ}	GND

Note:

 C_L = 50 pF or equivalent (includes jig and probe capacitance). R_L = R1 = 10 k Ω or equivalent.

 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω).

Figure 6. **Test circuit 2**





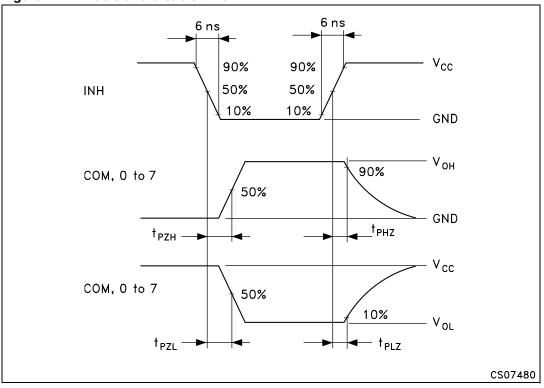




Figure 8. Selection path to output propagation delays

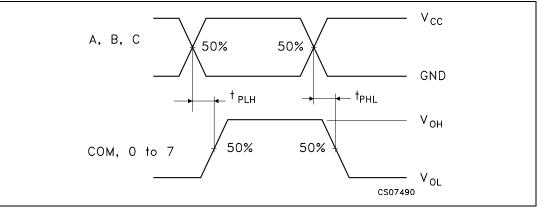


Figure 9. Input (COM, 0 to 7 in) to output (0 to 7 out, COM) propagation delays

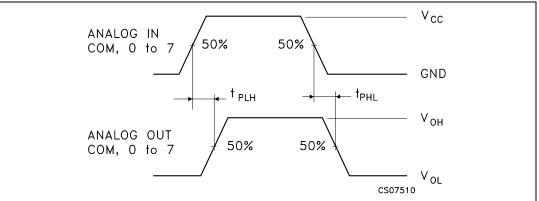


Figure 10. Channel resistance RON

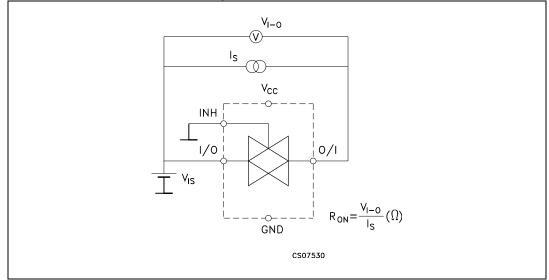
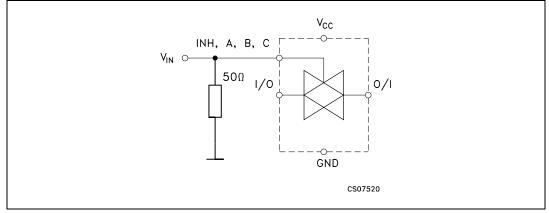


Figure 11. I_{CC} (opr)





3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK is an ST trademark.



3.1 SO-16 package information



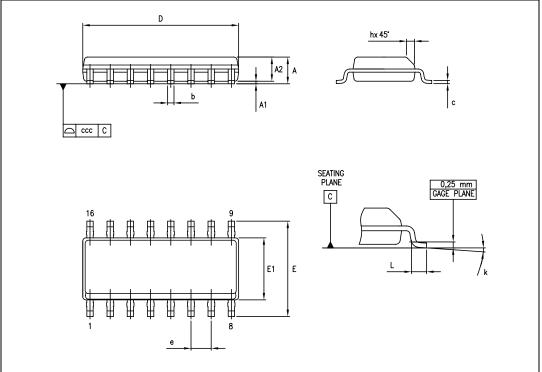


Table 10.SO-16 mechanical data

Symbol	Dimensions							
		Millimeters		Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.75			0.069		
A1	0.10		0.25	0.004		0.010		
A2	1.25			0.049				
b	0.31		0.51	0.012		0.020		
С	0.17		0.25	0.007		0.010		
D	9.80	9.90	10.00	0.386	0.390	0.394		
Е	5.80	6.00	6.20	0.228	0.236	0.244		
E1	3.80	3.90	4.00	0.150	0.154	0.157		
е		1.27			0.050			
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
k	0		8					
CCC			0.10			0.004		



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3.2 TSSOP16 package information



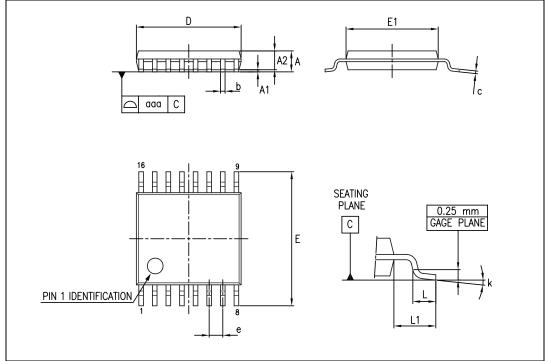


Table 11. TSSOP16 mechanical data

Symbol	Dimensions							
		Millimeters		Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.20			0.047		
A1	0.05		0.15	0.002		0.006		
A2	0.80	1.00	1.05	0.031	0.039	0.041		
b	0.19		0.30	0.007		0.012		
с	0.09		0.20	0.004		0.008		
D	4.90	5.00	5.10	0.193	0.197	0.201		
E	6.20	6.40	6.60	0.244	0.252	0.260		
E1	4.30	4.40	4.50	0.169	0.173	0.177		
е		0.65			0.0256			
k	0°		8°	0°		8°		
L	0.45	0.60	0.75	0.018	0.024	0.030		
L1		1.00			0.039			
aaa			0.10			0.004		

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4 Revision history

Date	Revision	Changes
05-Apr-2012	4	 Document reformatted. Added ESD charged device model feature on cover page. Added ESD values to <i>Table 4: Absolute maximum ratings</i>. Modified <i>Chapter 3: Package information</i>. Modified <i>Chapter 4: Ordering information</i>.
11-May-2012	5	 Added automotive-grade part number M74HC4851YRM13TR to <i>Table 12.: Order codes.</i> Added <i>Table 1.: Device summary</i> and Modified <i>Description</i> text on coverpage.
15-Jun-2012	6	 Updated Table 1: Device summary and Table 12: Order codes. Corrected ON resistance values in Features on page 1 Updated T_{op} in Table 5: Recommended operating conditions Added footnote 1 to Table 1: Device summary
26-Oct-2012	7	Updated ESD values in <i>Features</i> . Updated <i>Table 1</i> (added packaging and marking, updated note 1.) Removed <i>Table 12: Order codes</i> (<i>Section 4: Ordering information</i>). Minor corrections throughout document.



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